

-100V P-Channel Enhancement Mode MOSF

1. Product Information

1.1 Features

- ◇ Surface-mounted package
- ◇ Advanced SGT cell design

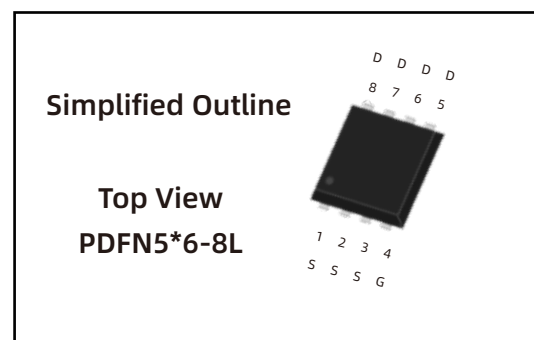
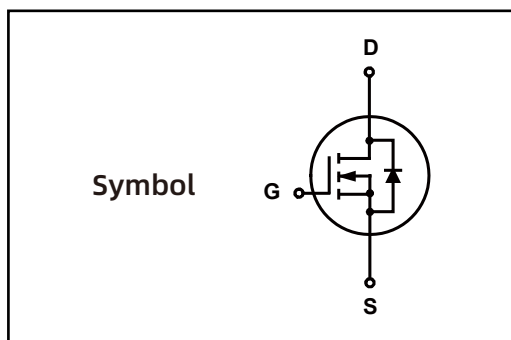
1.2 Applications

- ◇ BMS
- ◇ Drones
- ◇ High power inverter system
- ◇ Light electric vehicles

1.3 Quick reference

- ◇ $BV \cong -100\text{ V}$
- ◇ $P_{\text{tot}} \cong 52\text{ W}$
- ◇ $I_D \cong -27\text{ A}$
- ◇ $R_{\text{DS(ON)}} \cong 30\text{ m}\Omega @ V_{\text{GS}} = -10\text{ V}$
- ◇ $R_{\text{DS(ON)}} \cong 60\text{ m}\Omega @ V_{\text{GS}} = -4.5\text{ V}$

2. Pin Description



3. Marking Information

Product Name	Marking
LNS360P100G	LNS360P100G CYWWZZ XXXXXX

4. Limiting Values

Symbol	Parameter	Rating	Unit	
V_{DS}	Drain-Source Voltage	-100	V	
V_{GS}	Gate-Source Voltage	± 20	V	
I_D	Drain Current	$T_C = 25\text{ }^\circ\text{C}$	-27	A
		$T_C = 100\text{ }^\circ\text{C}$	-17	A
I_{DM}^{Note2}	Pulsed Source Current $TC = 25\text{ }^\circ\text{C}$	$T_C = 25\text{ }^\circ\text{C}$	-80	A
I_S	Diode Forward Current $TC = 25\text{ }^\circ\text{C}$	$T_C = 25\text{ }^\circ\text{C}$	-27	A
E_{AS}	Single Pulsed Avalanche Energy	$L = 1.0\text{mH}$	-242	mJ
P_{tot}	Total Power Dissipation	$TC = 25\text{ }^\circ\text{C}$	52	W
$R_{\theta JA}^{\text{Note1}}$	Thermal Resistance- Junction to Ambient		61	$^\circ\text{C} / \text{W}$
$R_{\theta JA}$	Thermal Resistance- Junction to Case		2.4	$^\circ\text{C} / \text{W}$
T_{stg}	Storage Temperature		-55~150	$^\circ\text{C}$
T_J	Junction Temperature		150	$^\circ\text{C}$

Note 1 : Surface Mounted on 1 in² pad area, $t \leq 10$ sec.

Note 2 : Pulse test; pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

Note 3 : Limited by bonding wire.

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
LNS360P100G	PDFN5*6-8L			5000	

Note: COMTECH defines " Green " as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

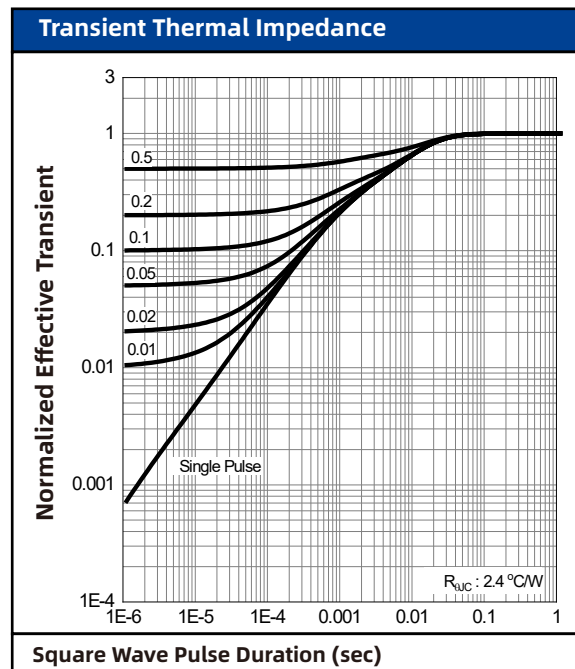
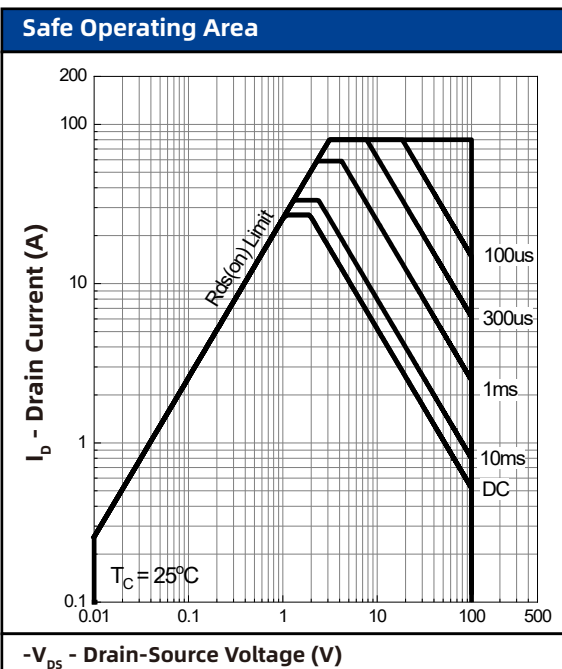
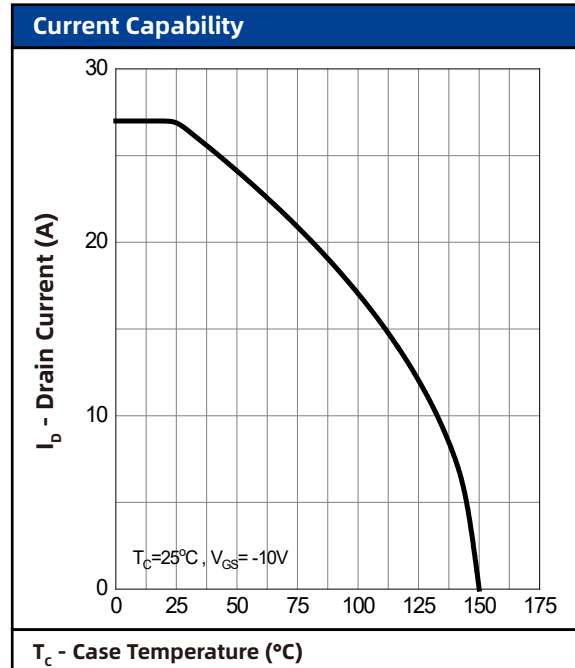
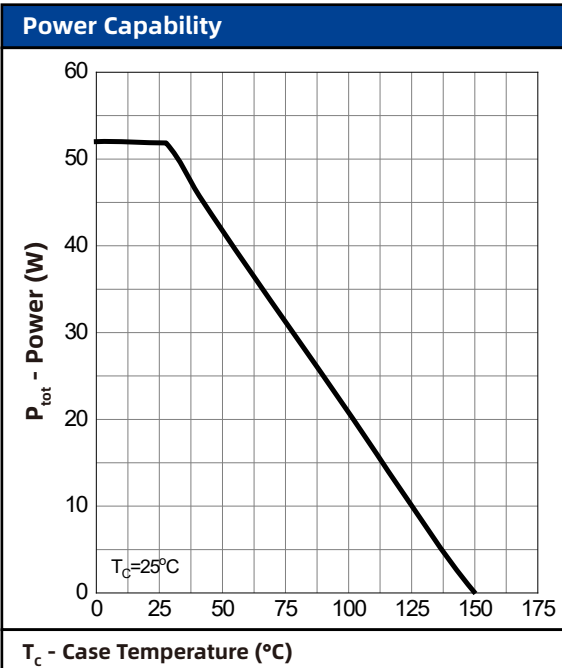
6. Electrical Characteristics ($T_A=25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = -250\text{ }\mu\text{A}$	-100	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = -250\text{ }\mu\text{A}$	1	-	-3	V
I_{DSS}	Drain Leakage Current	$V_{DS} = -80\text{ V}, V_{GS} = 0\text{ V}$	-	-	-1	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA
$R_{DS(on)}^a$	On-State Resistance	$V_{GS} = -10\text{ V}, I_{DS} = -10\text{ A}$	-	32	36	m Ω
		$V_{GS} = -4.5\text{ V}, I_{DS} = -5\text{ A}$	-	51	60	
Diode Characteristics						
V_{SD}^{Note1}	Diode Forward Voltage	$I_{SD} = -10\text{ A}, V_{GS} = 0\text{ V}$	-	-	-1.3	V
t_{rr}	Reverse Recovery Time	$I_{DS} = -10\text{ A}, V_{GS} = 0\text{ V}$	-	61	-	nS
Q_{rr}	Reverse Recovery Charge	$dl_{SD}/dt = -100\text{ A}/\mu\text{s}$	-	163	-	nC
Dynamic Characteristics^{Note2}						
C_{ISS}	Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = -50\text{ V}$ Frequency = 1 MHz	-	1297	-	pF
C_{OSS}	Output Capacitance		-	341	-	
C_{rSS}	Reverse Transfer Capacitance		-	28	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = -50\text{ V}, V_{GEN} = -10\text{ V},$ $R_G = 3.9\text{ }\Omega, R_L = 5\text{ }\Omega,$ $I_{DS} = -10\text{ A}$	-	9	-	nS
t_r	Turn-on Rise Time		-	12	-	
$t_d(off)$	Turn-off Delay Time		-	27	-	
t_f	Turn-off Fall Time		-	18	-	
Gate Charge Characteristics^{Note2}						
Q_g	Total Gate Charge	$V_{DS} = -50\text{ V}, V_{GS} = *-10\text{ V},$ $I_{DS} = -10\text{ A}$	-	27		nC
Q_{gs}	Gate-Source Charge		-	6.4		
Q_{gd}	Gate-Drain Charge		-	6.9		

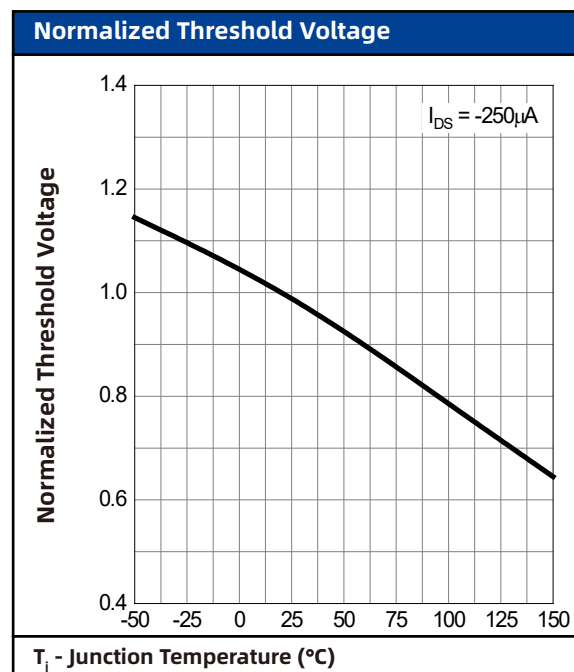
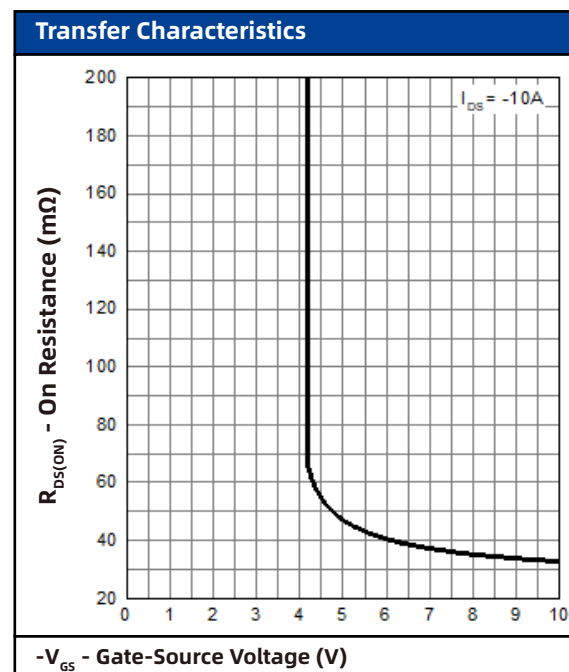
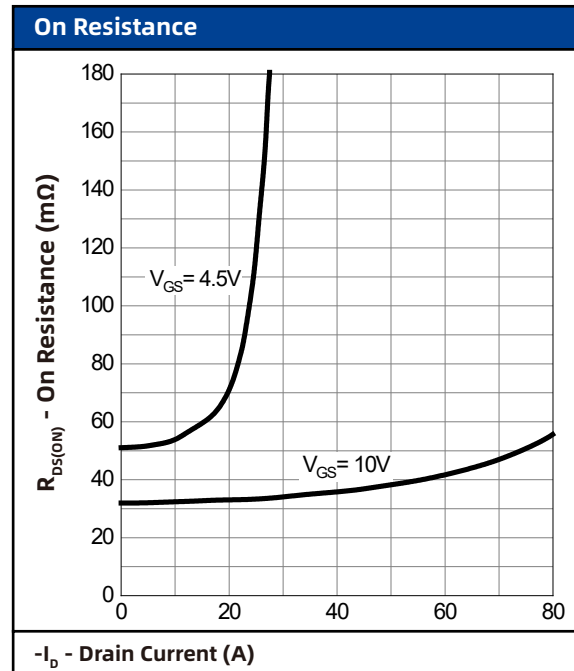
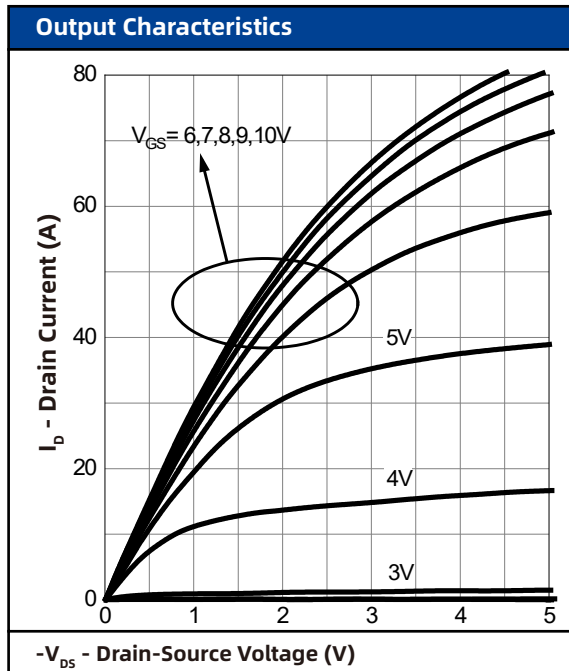
Note 1: Pulse test; pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

Note 2: Guaranteed by design, not subject to production testing.

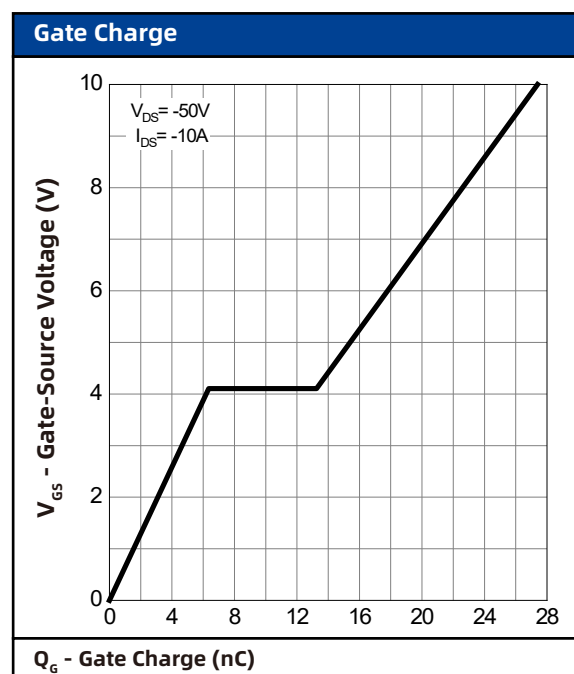
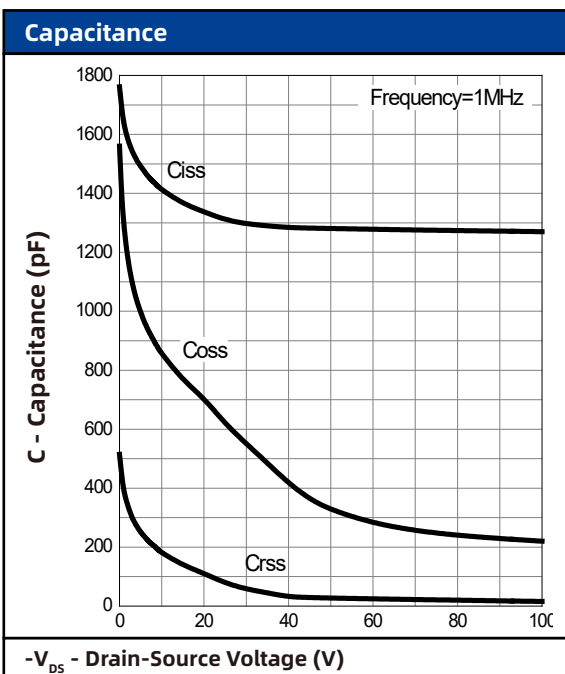
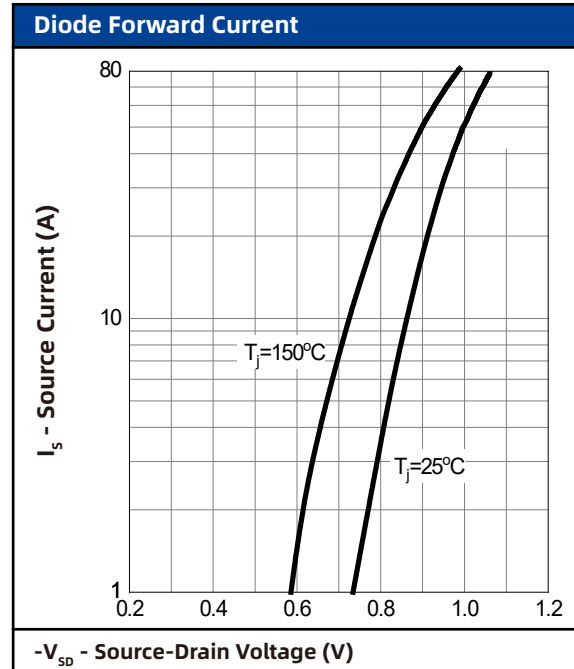
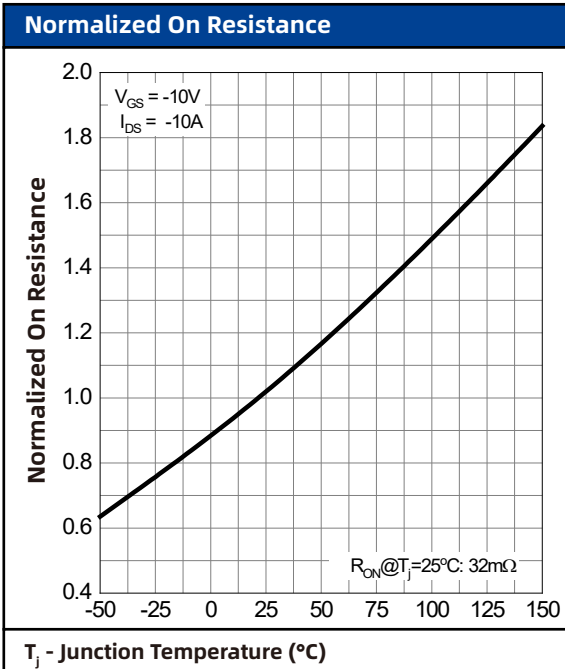
7. Typical Characteristics



7. Typical Characteristics (cont.)

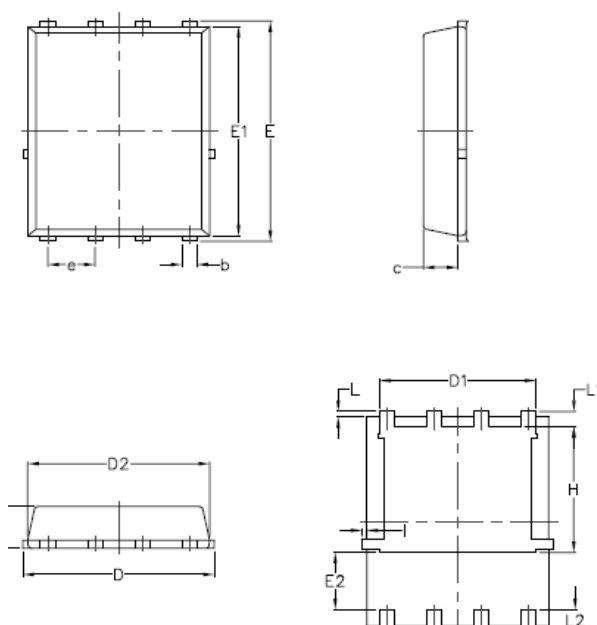


7. Typical Characteristics (cont.)



8. Package Dimensions

PDFN5x6 - 8L Package



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	1.03	1.17
b	0.34	0.48
c	0.824	0.970
D	4.80	5.40
D1	4.11	4.31
D2	4.80	5.00
E	5.95	6.15
E1	5.65	5.85
E2	1.40	-
E	1.27 BSC	
L	0.05	0.25
L1	0.38	0.50
L2	0.38	0.71
H	3.30	3.50
I	-	0.18